## FEATURES

- For high-speed switching applications
- Connected in series



## Absolute Maximum Ratings ( $\mathrm{T}_{\mathrm{a}}=25^{\circ} \mathrm{C}$ )

| Parameter | Symbol | Value | Unit |
| :---: | :---: | :---: | :---: |
| Repetitive Peak Reverse Voltage | $\mathrm{V}_{\text {RRM }}$ | 85 | V |
| Reverse Voltage | $\mathrm{V}_{\mathrm{R}}$ | 75 | V |
| Continuous Forward Current $\begin{array}{ll}\text { Single Diode Load } \\ \text { Double Diode Load }\end{array}$ | $\mathrm{I}_{\mathrm{F}}$ | $\begin{aligned} & 150 \\ & 130 \\ & \hline \end{aligned}$ | mA |
| Repetitive Peak Forward Current | $\mathrm{I}_{\text {FRM }}$ | 500 | mA |
| $\begin{array}{ll} \hline \text { Non-Repetitive Peak Forward Surge Current } & \begin{array}{l} \text { at } t=1 \mu \mathrm{~s} \\ \\ \\ \\ \\ \text { at } t=1 \mathrm{~ms} \\ \text { at } t=1 \mathrm{~s} \end{array} \\ \hline \end{array}$ | $I_{\text {FSM }}$ | $\begin{gathered} \hline 4 \\ 1 \\ 0.5 \end{gathered}$ | A |
| Total Power Dissipation | $\mathrm{P}_{\text {tot }}$ | 200 | mW |
| Thermal Resistance from Junction to Ambient | $\mathrm{R}_{\text {өJA }}$ | 625 | ${ }^{\circ} \mathrm{C} / \mathrm{W}$ |
| Junction Temperature | $\mathrm{T}_{\mathrm{j}}$ | 150 | ${ }^{\circ} \mathrm{C}$ |
| Storage Temperature Range | $\mathrm{T}_{\text {stg }}$ | -55 to +150 | ${ }^{\circ} \mathrm{C}$ |

## Characteristics at $\mathrm{T}_{\mathrm{a}}=\mathbf{2 5}^{\circ} \mathrm{C}$

| Parameter | Symbol | Max. | Unit |
| :---: | :---: | :---: | :---: |
| $\begin{aligned} & \text { Forward Voltage } \\ & \text { at } I_{F}=1 \mathrm{~mA} \\ & \text { at } I_{F}=10 \mathrm{~mA} \\ & \text { at } I_{F}=50 \mathrm{~mA} \\ & \text { at } I_{F}=150 \mathrm{~mA} \end{aligned}$ | $V_{F}$ | $\begin{gathered} 0.715 \\ 0.855 \\ 1 \\ 1.25 \\ \hline \end{gathered}$ | V |
| $\begin{aligned} & \text { Reverse Current } \\ & \text { at } V_{R}=25 \mathrm{~V} \\ & \text { at } \mathrm{V}_{\mathrm{R}}=75 \mathrm{~V} \\ & \text { at } \mathrm{V}_{\mathrm{R}}=25 \mathrm{~V}, \mathrm{~T}_{\mathrm{j}}=150^{\circ} \mathrm{C} \\ & \text { at } \mathrm{V}_{\mathrm{R}}=75 \mathrm{~V}, \mathrm{~T}_{j}=150^{\circ} \mathrm{C} \end{aligned}$ | $I_{\text {R }}$ | $\begin{gathered} 30 \\ 1 \\ 30 \\ 50 \end{gathered}$ | nA <br> $\mu \mathrm{A}$ <br> $\mu \mathrm{A}$ <br> $\mu \mathrm{A}$ |
| Diode Capacitance at $V_{R}=0, f=1 \mathrm{MHz}$ | $\mathrm{C}_{\text {d }}$ | 1.5 | pF |
| Reverse Recovery Time at $I_{F}=I_{R}=10 \mathrm{~mA}, I_{r r}=0.1 \mathrm{XI} \mathrm{I}_{\mathrm{R}}, \mathrm{R}_{\mathrm{L}}=100 \Omega$ | $\mathrm{t}_{\text {r }}$ | 4 | ns |

TWGME

## Typical Characteristics



Based on square wave currents
$\mathrm{T}_{\mathrm{j}}=25^{\circ} \mathrm{C}$ prior to surge.
Maximum permissible non-repetitive peak forward current as a function of pulse duration.


Reverse current as a function of junction temperature.

$\mathrm{f}=1 \mathrm{MHz} ; \mathrm{T}_{\mathrm{j}}=25^{\circ} \mathrm{C}$.
Diode capacitance as a function of reverse voltage; typical values.

## PACKAGE OUTLINE

Plastic surface mounted package; 3 leads


| Symbol | Dimension in Millimeters |  |
| :---: | :---: | :---: |
|  | Min | Max |
| A | 0.900 | 1.100 |
| A1 | 0.000 | 0.100 |
| A2 | 0.900 | 1.000 |
| b | 0.200 | 0.400 |
| c | 0.080 | 0.150 |
| D | 2.000 | 2.200 |
| E | 1.150 | 1.350 |
| E1 | 2.150 | 2.450 |
| e | 0.650 TYP. |  |
| e1 | 1.200 | 1.400 |
| L | 0.525 REF. |  |
| L1 | 0.260 | 0.460 |
| $\theta$ | $0^{\circ}$ | $8^{\circ}$ |

